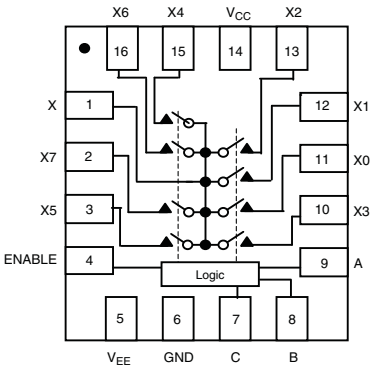
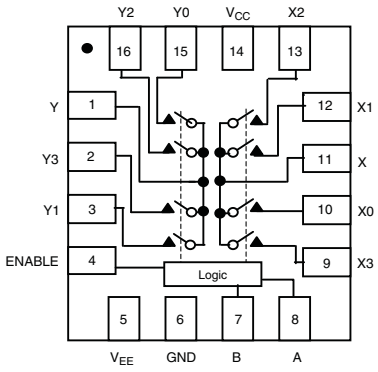
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG4051A
mQFN-16



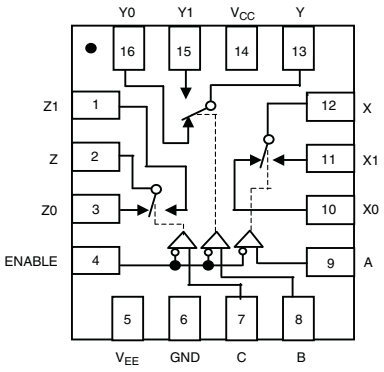
Top View

DG4052A
mQFN-16

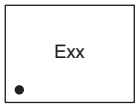


Top View

DG4053A
mQFN-16



Top View



Device Marking: Exx for DG4051A
(miniQFN16) Fxx for DG4052A
Gxx for DG4053A
xx = Date/Lot Traceability Code

TRUTH TABLE

Enable Input	Select Inputs			On Switches		
	C	B	A	DG4051A	DG4052A	DG4053A
H	X	X	X	All Switches Open	All Switches Open	All Switches Open
L	L	L	L	X to X0	X to X0, Y to Y0	X to X0, Y to Y0, Z to Z0
L	L	L	H	X to X1	X to X1, Y to Y1	X to X1, Y to Y0, Z to Z0
L	L	H	L	X to X2	X to X2, Y to Y2	X to X0, Y to Y1, Z to Z0
L	L	H	H	X to X3	X to X3, Y to Y3	X to X1, Y to Y1, Z to Z0
L	H	L	L	X to X4	X to X0, Y to Y0	X to X0, Y to Y0, Z to Z1
L	H	L	H	X to X5	X to X1, Y to Y1	X to X1, Y to Y0, Z to Z1
L	H	H	L	X to X6	X to X2, Y to Y2	X to X0, Y to Y1, Z to Z1
L	H	H	H	X to X7	X to X3, Y to Y3	X to X1, Y to Y1, Z to Z1

ORDERING INFORMATION

Temp Range	Package	Part Number
DG4051A, DG4052A, DG4053A		
- 40 °C to 125 °C[a]	16-Pin TSSOP	DG4051AEQ-T1-E3 DG4052AEQ-T1-E3 DG4053AEQ-T1-E3
	16-Pin miniQFN	DG4051AEN-T1-E4 DG4052AEN-T1-E4 DG4053AEN-T1-E4

Notes:
a. - 40 °C to 85 °C datasheet limits apply.

ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted			
Parameter		**Limit**	**Unit**
V+ to V-		14	V
GND to V-		7	
Digital Inputs[a], V_S, V_D		(V-) - 0.3 to (V+) + 0.3 or 30 mA, whichever occurs first	
Continuous Current (Any terminal)		30	mA
Peak Current, S or D (Pulsed 1 ms, 10 % duty cycle)		100	
Storage Temperature		- 65 to 150	°C
Power Dissipation[b]	16-Pin TSSOP[c]	450	mW
	16-Pin miniQFN[d, e]	525	
Thermal Resistance[b]	16-Pin TSSOP	178	°C/W
	16-Pin miniQFN[e]	152	

Notes:
a. Signals on SX, DX, or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 5.6 mW/°C above 70 °C.
d. Derate 6.6 mW/°C above 70 °C.
e. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

SPECIFICATIONS FOR DUAL SUPPLIES

Parameter	**Symbol**	**Test Conditions Unless Otherwise Specified** V_{CC} = + 5 V, V_{EE} = - 5 V $V_{IN(A, B, C and ENABLE)}$ = 2.0 V, 0.8 V[a]		**Temp.[b]**	**Typ.[c]**	- 40 °C to 125 °C **Min.[d]**	- 40 °C to 125 °C **Max.[d]**	- 40 °C to 85 °C **Min.[d]**	- 40 °C to 85 °C **Max.[d]**	**Unit**
Analog Switch										
Analog Signal Range[e]	V_{ANALOG}		Full		- 5	5	- 5	5	V	
On-Resistance	R_{ON}	I_S = 1 mA, V_D = - 3 V, 0 V, + 3 V	Room Full	66		100 125		100 118	Ω	
On-Resistance Match	ΔR_{ON}	I_S = 1 mA, V_D = ± 3 V	Room Full	3		6 10		6 8		
On-Resistance Flatness	$R_{FLATNESS}$	I_S = 1 mA, V_D = - 3 V, 0 V, + 3 V	Room Full	12		16 20		16 18		
Switch Off Leakage Current	$I_{S(off)}$	V+ = 5.5 V, V- = - 5.5 V, V_D = ± 4.5 V, V_S = ∓ 4.5 V	Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5	nA	
	$I_{D(off)}$		Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5		
Channel On Leakage Current	$I_{D(on)}$	V+ = 5.5 V, V- = - 5.5 V, V_S = V_D = ± 4.5 V	Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5		
Digital Control										
Input Current, V_{IN} Low	I_{IL}	$V_{IN(A, B, C and ENABLE)}$ under test = 0.8 V	Full	0.01	- 1	1	- 1	1	µA	
Input Current, V_{IN} High	I_{IH}	$V_{IN(A, B, C and ENABLE)}$ under test = 2.0 V	Full	0.01	- 1	1	- 1	1		
Input Capacitance[e]	C_{IN}	f = 1 MHz	Room	3.4					pF	
Dynamic Characteristics										
Off Isolation	OIRR	R_L = 50 Ω, C_L = 1 pF	f = 10 MHz	Room	67					dB
			f = 100 MHz	Room	46					
Channel-to-Channel Crosstalk	X_{TALK}		f = 10 MHz	Room	67					
			f = 100 MHz	Room	47					
Bandwith, 3 dB	BW	R_L = 50 Ω	DG4051A	Room	330					MHz
			DG4052A	Room	450					
			DG4053A	Room	730					

SPECIFICATIONS FOR DUAL SUPPLIES

Parameter	Symbol	Test Conditions Unless Otherwise Specified V_{CC} = + 5 V, V_{EE} = - 5 V $V_{IN(A, B, C \text{ and ENABLE})}$ = 2.0 V, 0.8 V[a]		Temp.[b]	Typ.[c]	- 40 °C to 125 °C Min.[d]	- 40 °C to 125 °C Max.[d]	- 40 °C to 85 °C Min.[d]	- 40 °C to 85 °C Max.[d]	Unit
Dynamic Characteristics										
Transition Time	t_{TRANS}	R_L = 300 Ω, C_L = 35 pF see figure 1, 2, 3		Room Full	36		110 127		110 117	ns
Enable Turn-On Time	t_{ON}			Room Full	31		108 119		108 114	
Enable Turn-Off Time	t_{OFF}			Room Full	29		92 103		92 98	
Break-Before-Make Time Delay	t_D			Room Full		1		1		
Charge Injection[e]	Q	V_g = 0 V, R_g = 0 Ω, C_L = 1 nF		Room	0.25					pC
Off Isolation[e]	OIRR	R_L = 50 Ω, C_L = 1 pF f = 100 kHz		Room	< - 90					dB
Channel-to-Channel Crosstalk[e]	X_{TALK}			Room	< - 90					
Source Off Capacitance[e]	$C_{S(off)}$	f = 1 MHz	DG4051A	Room	3					pF
			DG4052A	Room	3					
			DG4053A	Room	3					
Drain Off Capacitance[e]	$C_{D(off)}$	f = 1 MHz	DG4051A	Room	12					
			DG4052A	Room	7					
			DG4053A	Room	4					
Channel On Capacitance[e]	$C_{D(on)}$	f = 1 MHz	DG4051A	Room	17					
			DG4052A	Room	13					
			DG4053A	Room	11					
Total Harmonic Distortion[e]	THD	Signal = 5 V_{RMS}, 20 Hz to 20 kHz, R_L = 600 Ω		Room	0.28					%
Power Supplies										
Power Supply Current	I+	V_{CC} = + 5 V, V_{EE} = - 5 V $V_{IN(A, B, C \text{ and ENABLE})}$ = 0 or 5 V		Room Full	0.05		1 10		1 10	µA
Negative Supply Current	I-			Room Full	- 0.05	- 1 - 10		- 1 - 10		
Ground Current	I_{GND}			Room Full	- 0.05	- 1 - 10		- 1 - 10		

SPECIFICATIONS FOR UNIPOLAR SUPPLIES

Parameter	Symbol	Test Conditions Unless Otherwise Specified V_{CC} = + 5 V, V_{EE} = 0 V $V_{IN(A, B, C \text{ and ENABLE})}$ = 2.0 V, 0.8 V[a]		Temp.[b]	Typ.[c]	- 40 °C to 125 °C Min.[d]	- 40 °C to 125 °C Max.[d]	- 40 °C to 85 °C Min.[d]	- 40 °C to 85 °C Max.[d]	Unit
Analog Switch										
Analog Signal Range[e]	V_{ANALOG}			Full		0	5	0	5	V
On-Resistance	R_{ON}	I_S = 1 mA, V_D = 0 V, + 3.5 V		Room Full	107		165 205		165 194	Ω
On-Resistance Match	ΔR_{ON}	I_S = 1 mA, V_D = + 3.5 V		Room Full	3.2		8 13		8 11	Ω
On-Resistance Flatness	$R_{FLATNESS}$	I_S = 1 mA, V_D = 0 V, + 3 V		Room Full	19		26 30		26 28	Ω
Switch Off Leakage Current	$I_{S(off)}$	V+ = + 5.5 V, V- = 0 V V_D = 1 V/4.5 V, V_S = 4.5 V/1 V		Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5	nA
	$I_{D(off)}$			Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5	nA
Channel On Leakage Current	$I_{D(on)}$	V+ = + 5.5 V, V- = 0 V V_D = V_S = 1 V/4.5 V		Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5	nA
Digital Control										
Input Current, V_{IN} Low	I_L	$V_{IN(A, B, C \text{ and ENABLE})}$ under test = 0.8 V		Full	0.01	- 1	1	- 1	1	µA
Input Current, V_{IN} High	I_H	$V_{IN(A, B, C \text{ and ENABLE})}$ under test = 2.0 V		Full	0.01	- 1	1	- 1	1	µA
Dynamic Characteristics										
Transition Time	t_{TRANS}	R_L = 300 Ω, C_L = 35 pF See Figure 1, 2, 3		Room Full	38		121 143		121 134	ns
Enable Turn-On Time	t_{ON}			Room Full	38		110 126		110 119	ns
Enable Turn-Off Time	t_{OFF}			Room Full	38		103 118		103 111	ns
Break-Before-Make Time Delay	t_D			Room Full		1		1		ns
Charge Injection[e]	Q	V_g = 0 V, R_g = 0 Ω, C_L = 1 nF		Full	0.5					pC
Off Isolation[e]	OIRR	R_L = 50 Ω, C_L = 1 pF f = 100 kHz		Room	< - 90					dB
Channel-to-Channel Crosstalk[e]	X_{TALK}			Room	< - 90					dB
Source Off Capacitance[e]	$C_{S(off)}$	f = 1 MHz	DG4051A	Room	3					pF
			DG4052A	Room	3					pF
			DG4053A	Room	4					pF
Drain Off Capacitance[e]	$C_{D(off)}$	f = 1 MHz	DG4051A	Room	13					pF
			DG4052A	Room	8					pF
			DG4053A	Room	5					pF
Channel On Capacitance[e]	$C_{D(on)}$	f = 1 MHz	DG4051A	Room	18					pF
			DG4052A	Room	14					pF
			DG4053A	Room	11					pF
Power Supplies										
Power Supply Current	I+	$V_{IN(A, B, C \text{ and ENABLE})}$ = 0 V or 5 V		Room Full	0.05		1 10		1 10	µA
Negative Supply Current	I-			Room Full	- 0.05	- 1 - 10		- 1 - 10		µA
Ground Current	I_{GND}			Room Full	- 0.05	- 1 - 10		- 1 - 10		µA

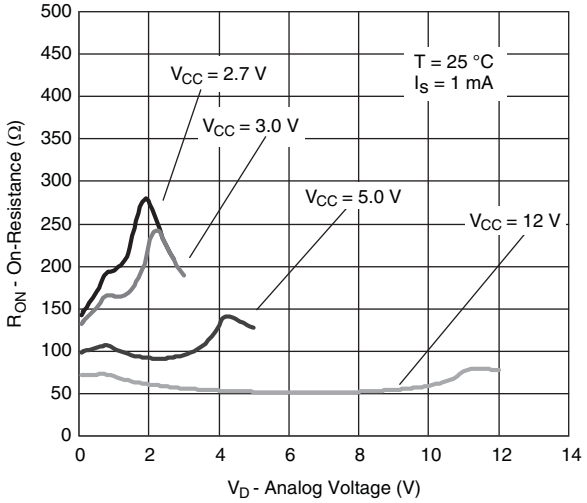
SPECIFICATIONS FOR UNIPOLAR SUPPLIES

Parameter	Symbol	Test Conditions Unless Otherwise Specified V_{CC} = + 3 V, V_{EE} = 0 V $V_{IN(A, B, C \text{ and ENABLE})}$ = 1.4 V, 0.6 V[a]		Temp.[b]	Typ.[c]	- 40 °C to 125 °C Min.[d]	- 40 °C to 125 °C Max.[d]	- 40 °C to 85 °C Min.[d]	- 40 °C to 85 °C Max.[d]	Unit
Analog Switch										
Analog Signal Range[e]	V_{ANALOG}			Full		0	3	0	3	V
On-Resistance	R_{ON}	I_S = 1 mA, V_D = 1.5 V		Room Full	175		265 310		265 298	Ω
Switch Off Leakage Current	$I_{S(off)}$	V+ = + 3.3 V, V- = 0 V V_D = 0.3 V/3.0 V, V_S = 3.0 V/0.3 V		Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5	nA
	$I_{D(off)}$			Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5	
Channel On Leakage Current	$I_{D(on)}$	V+ = + 3.3 V, V- = 0 V V_D = V_S = 0.3 V/3.0 V		Room Full	± 0.02	- 1 - 50	1 50	- 1 - 5	1 5	
Digital Control										
Input Current, V_{IN} Low	I_L	$V_{IN(A, B, C \text{ and ENABLE})}$ under test = 0.6 V		Full	0.01	- 1	1	- 1	1	µA
Input Current, V_{IN} High	I_H	$V_{IN(A, B, C \text{ and ENABLE})}$ under test = 1.4 V		Full	0.01	- 1	1	- 1	1	
Dynamic Characteristics										
Transition Time	t_{TRANS}	R_L = 300 Ω, C_L = 35 pF see figure 1, 2, 3		Room Full	81		172 218		172 194	ns
Enable Turn-On Time	t_{ON}			Room Full	71		151 183		151 167	
Enable Turn-Off Time	t_{OFF}			Room Full	69		138 161		138 151	
Break-Before-Make Time Delay	t_D			Room Full		1		1		
Charge Injection[e]	Q	V_g = 0 V, R_g = 0 Ω, C_L = 1 nF		Room	0.5					pC
Off Isolation[e]	OIRR	R_L = 50 Ω, C_L = 1 pF f = 100 kHz		Room	< - 90					dB
Channel-to-Channel Crosstalk[e]	X_{TALK}			Room	< - 90					
Source Off Capacitance[e]	$C_{S(off)}$	f = 1 MHz	DG4051A	Room	4					pF
			DG4052A	Room	3					
			DG4053A	Room	4					
Drain Off Capacitance[e]	$C_{D(off)}$	f = 1 MHz	DG4051A	Room	14					
			DG4052A	Room	8					
			DG4053A	Room	5					
Channel On Capacitance[e]	$C_{D(on)}$	f = 1 MHz	DG4051A	Room	19					
			DG4052A	Room	14					
			DG4053A	Room	11					
Power Supplies										
Power Supply Current	I+	$V_{IN(A, B, C \text{ and ENABLE})}$ = 0 V or 3 V		Room Full	0.05		1 10		1 10	µA
Negative Supply Current	I-			Room Full	- 0.05	- 1 - 10		- 1 - 10		
Ground Current	I_{GND}			Room Full	- 0.05	- 1 - 10		- 1 - 10		

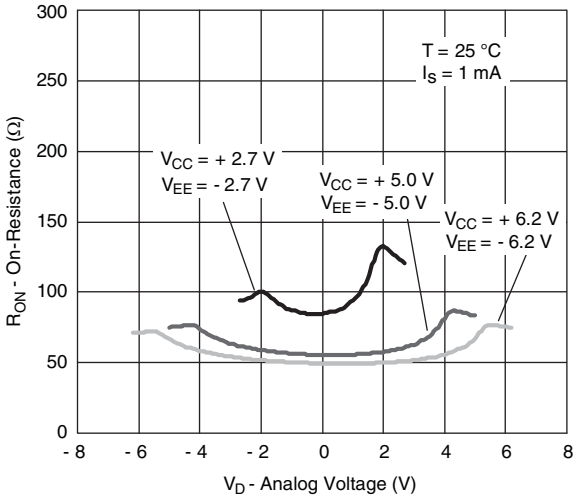
Notes:
a. V_{IN} = input voltage to perform proper function.
b. Room = 25 °C, Full = as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
e. Guaranteed by design, not subject to production test.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

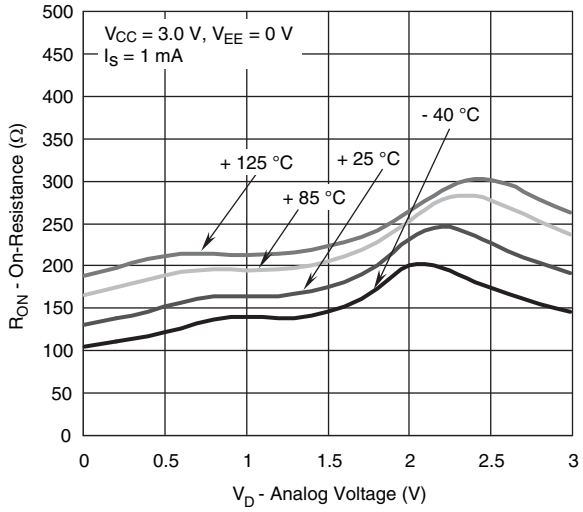
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



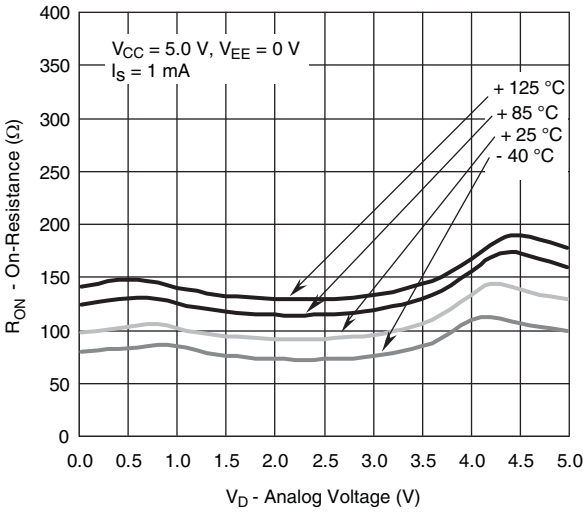
On-Resistance vs. V_D and Single Supply Voltage



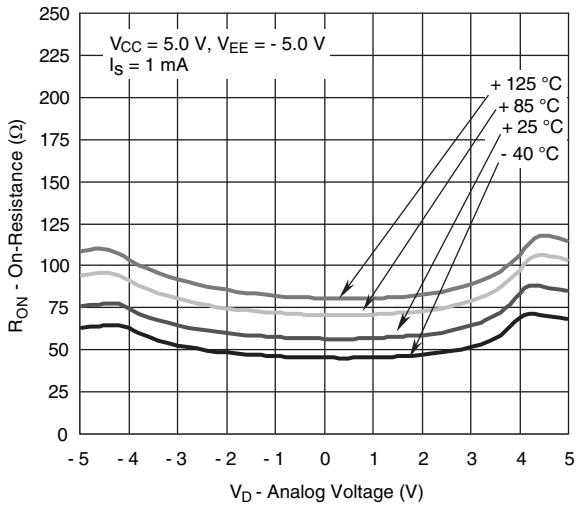
On-Resistance vs. V_D and Dual Supply Voltage



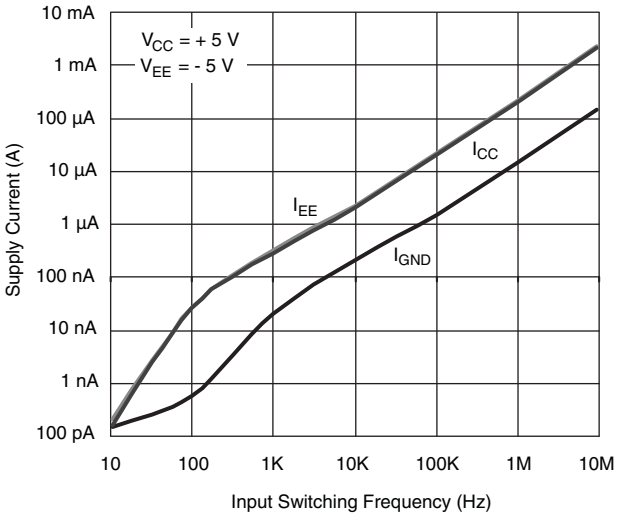
On-Resistance vs. Analog Voltage and Temperature at V_{CC} = + 3 V, V_{EE} = 0 V



On-Resistance vs. Analog Voltage and Temperature at V_{CC} = + 5 V, V_{EE} = 0 V

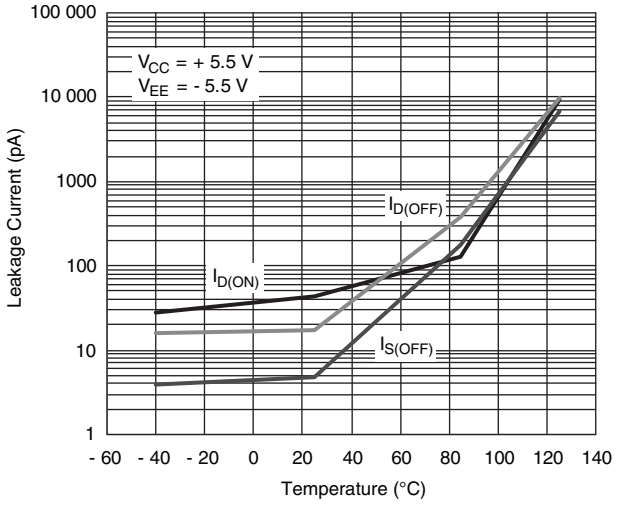


On-Resistance vs. Analog Voltage and Temperature at V_{CC} = + 5 V, V_{EE} = - 5 V

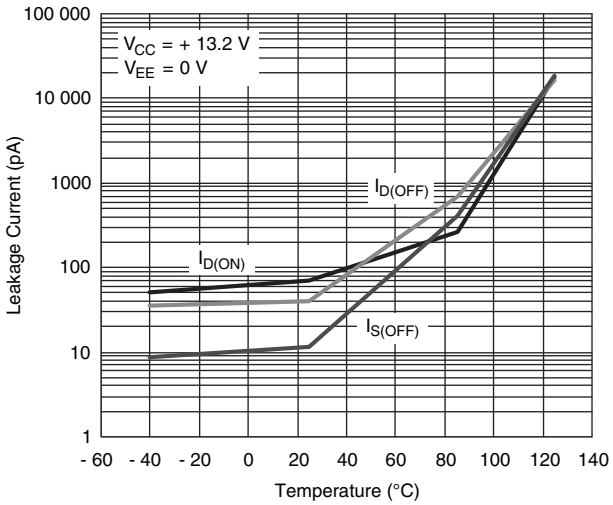


Supply Current vs. Input Switching Frequency

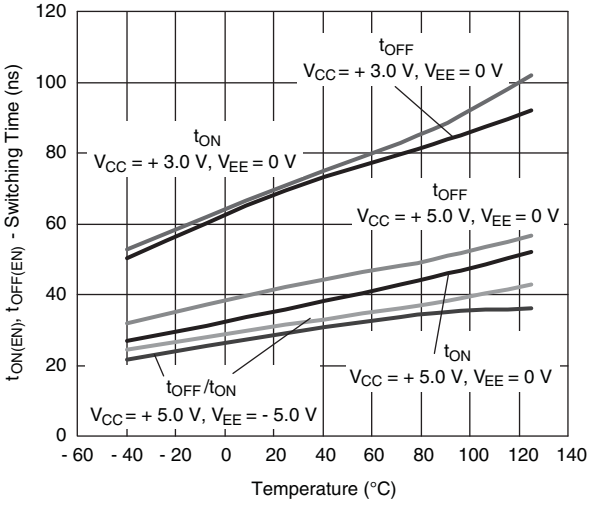
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



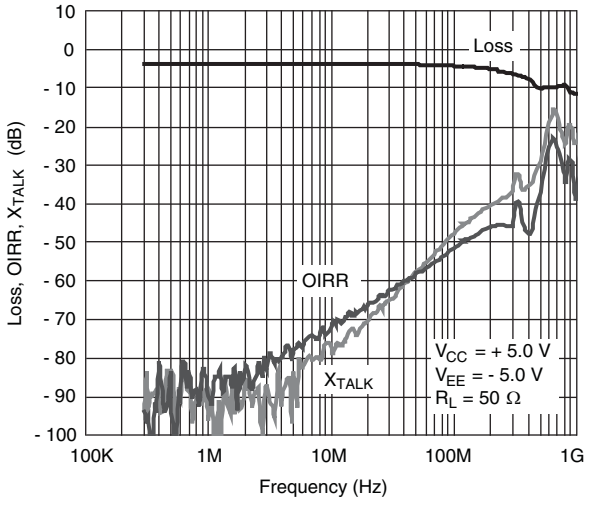
Leakage Current vs. Temperature



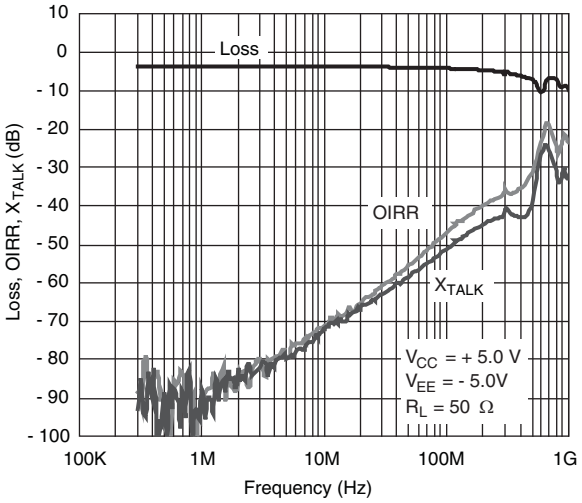
Leakage Current vs. Temperature



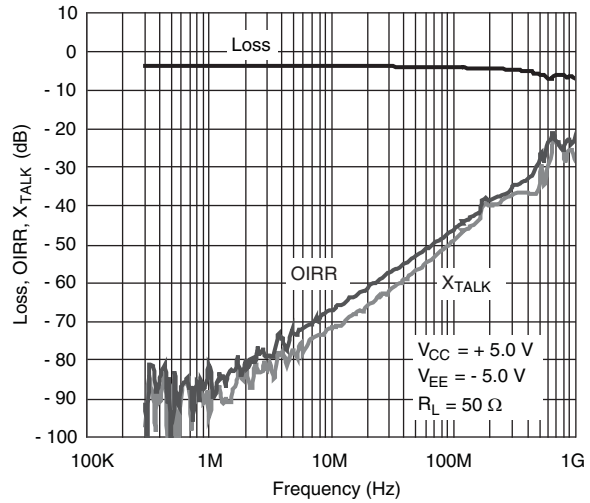
Switching Time vs. Temperature



DG4051A Insertion Loss, Off-Isolation, Crosstalk vs. Frequency at ± 5 V Supply

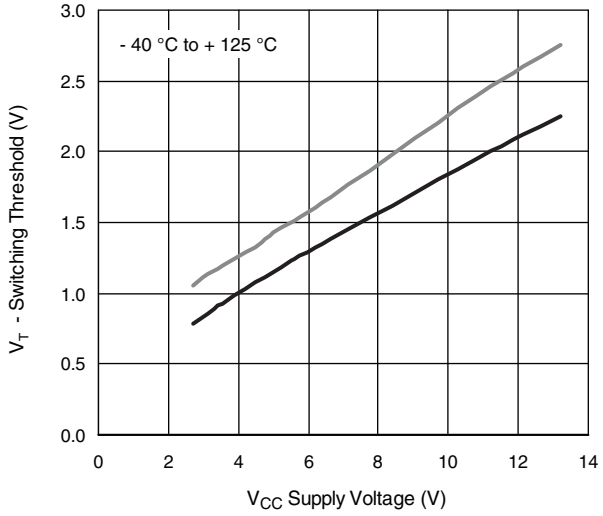


DG4052A Insertion Loss, Off-Isolation, Crosstalk vs. Frequency at ± 5 V Supply

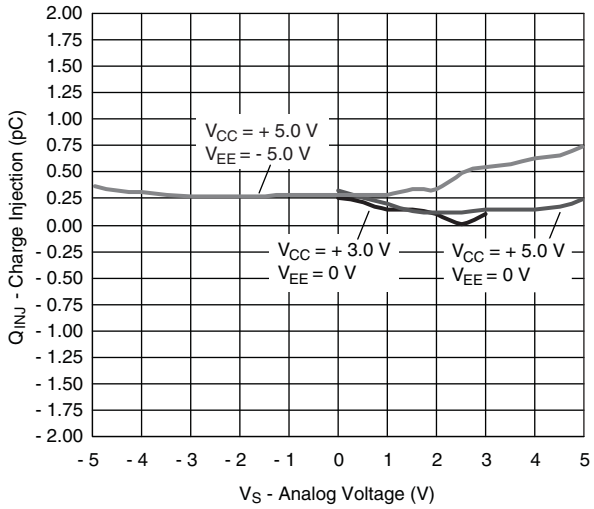


DG4053A Insertion Loss, Off-Isolation, Crosstalk vs. Frequency at ± 5 V Supply

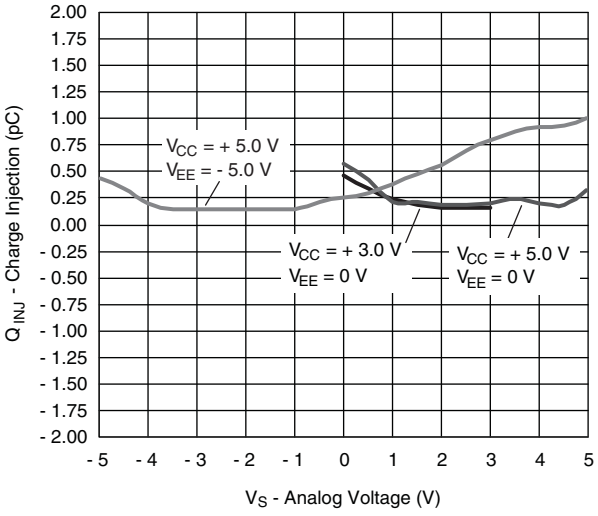
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



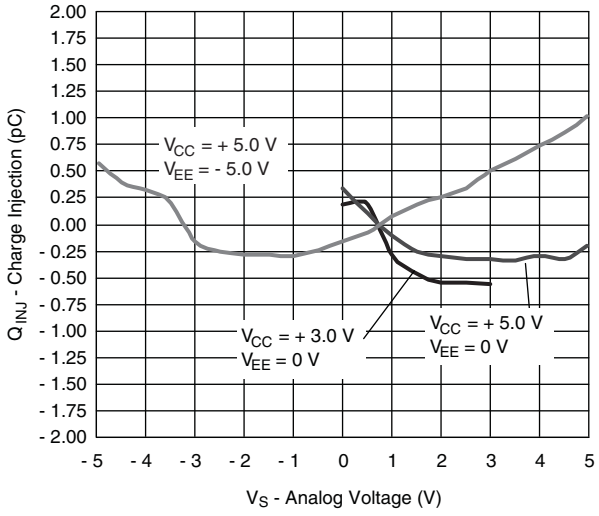
Switching Threshold vs. V_{CC} Supply Voltage



DG4051A Charge Injection vs. Analog Voltage



DG4052A Charge Injection vs. Analog Voltage



DG4053A Charge Injection vs. Analog Voltage

TEST CIRCUITS

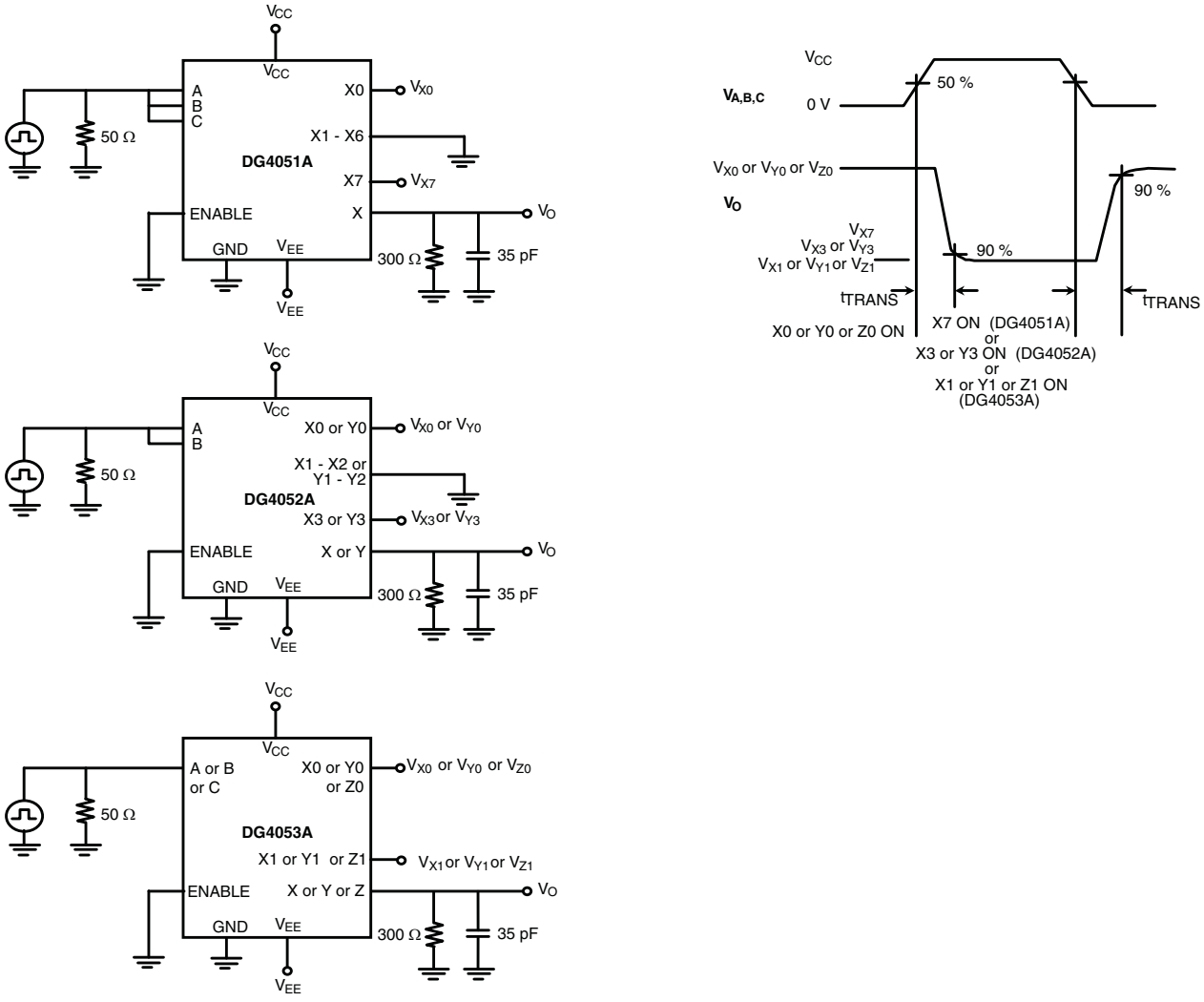
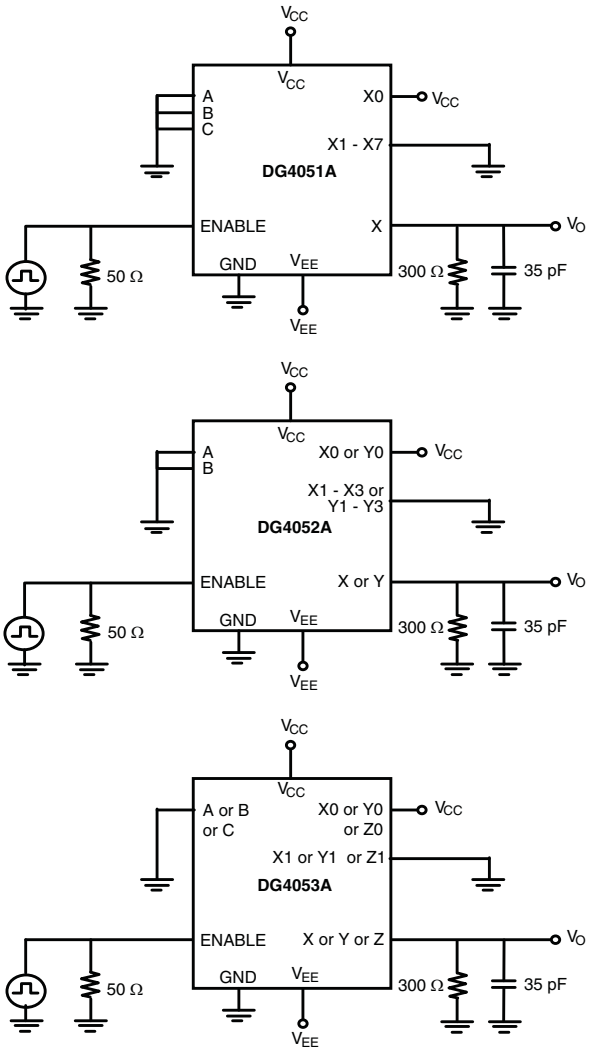


Figure 1. Transition Time

TEST CIRCUITS



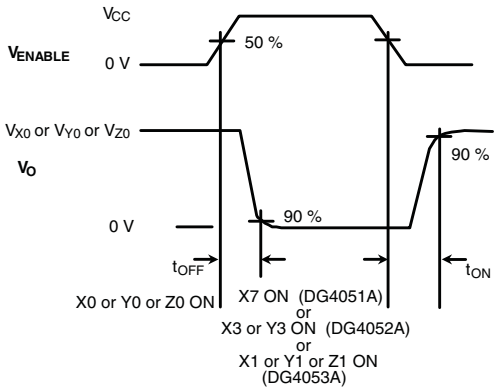


Figure 2. Enable Switching Time

TEST CIRCUITS

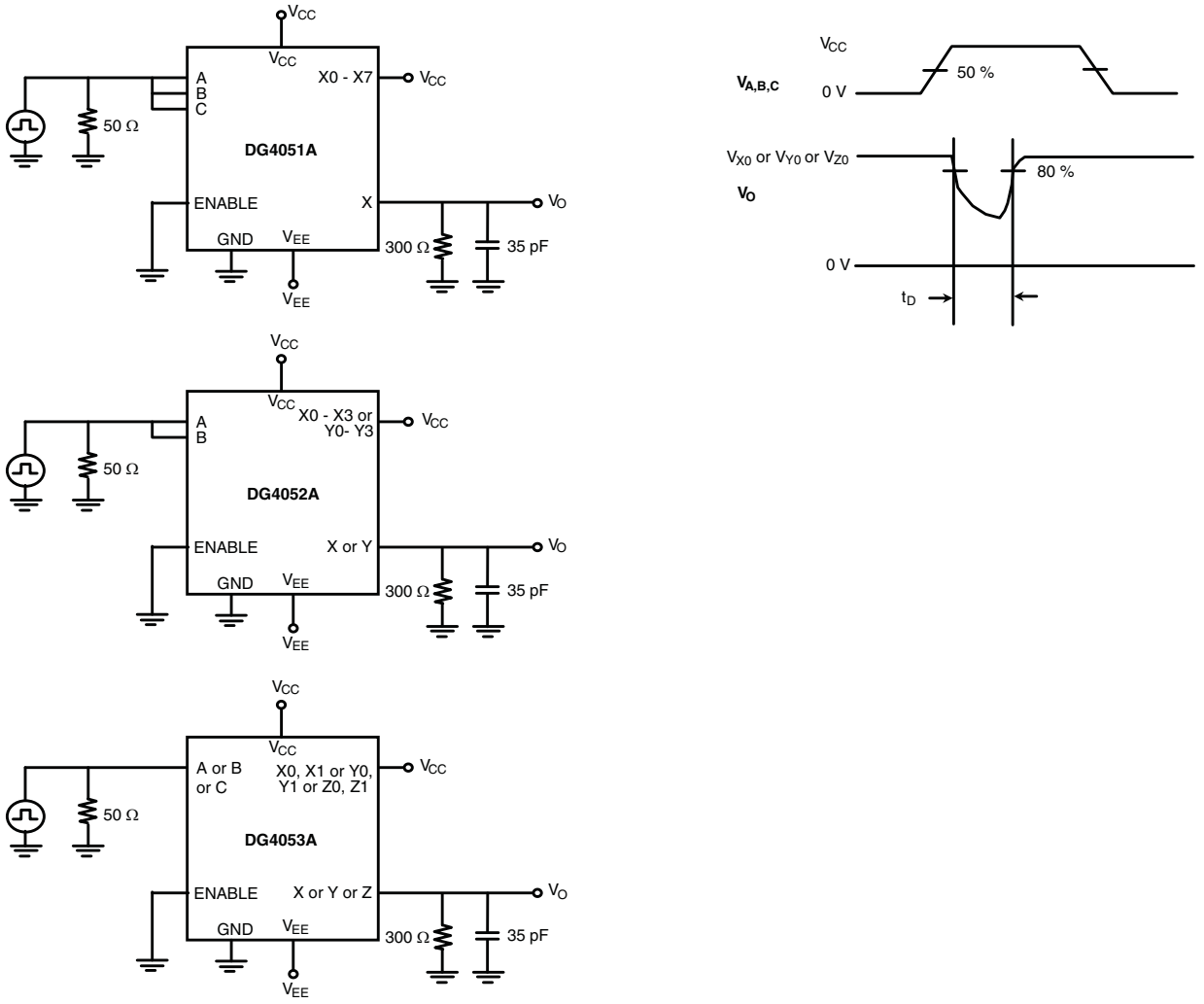


Figure 3. Break-Before-Make

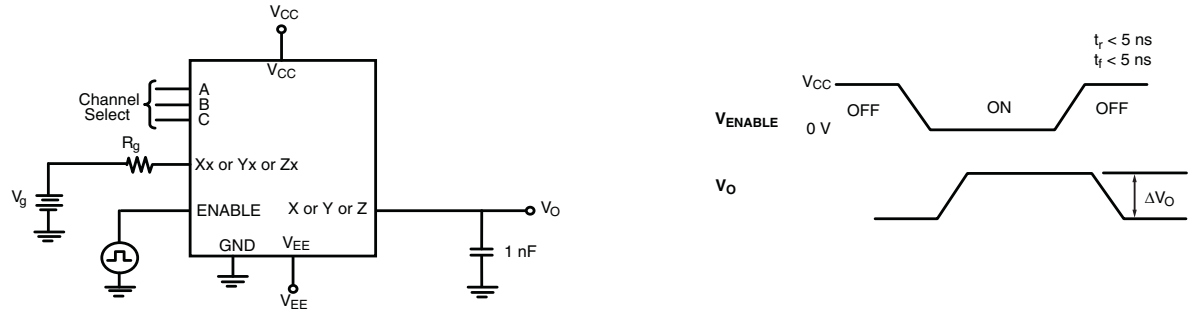


Figure 4. Charge Injection

TEST CIRCUITS

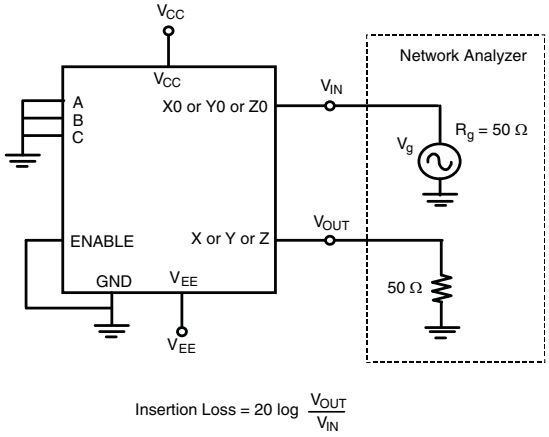


Figure 5. Insertion Loss

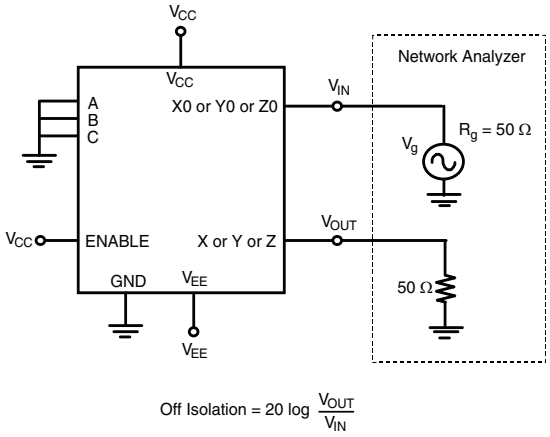


Figure 6. Off Isolation

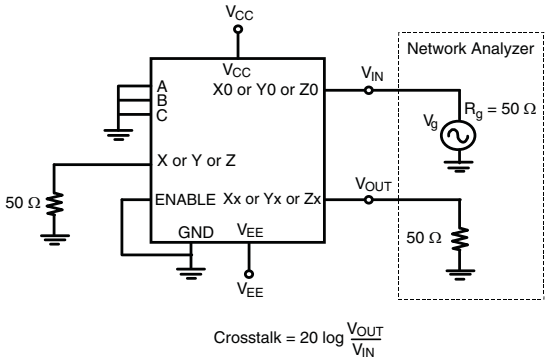


Figure 7. Crosstalk

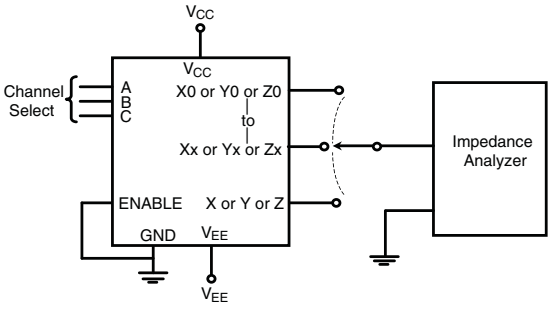
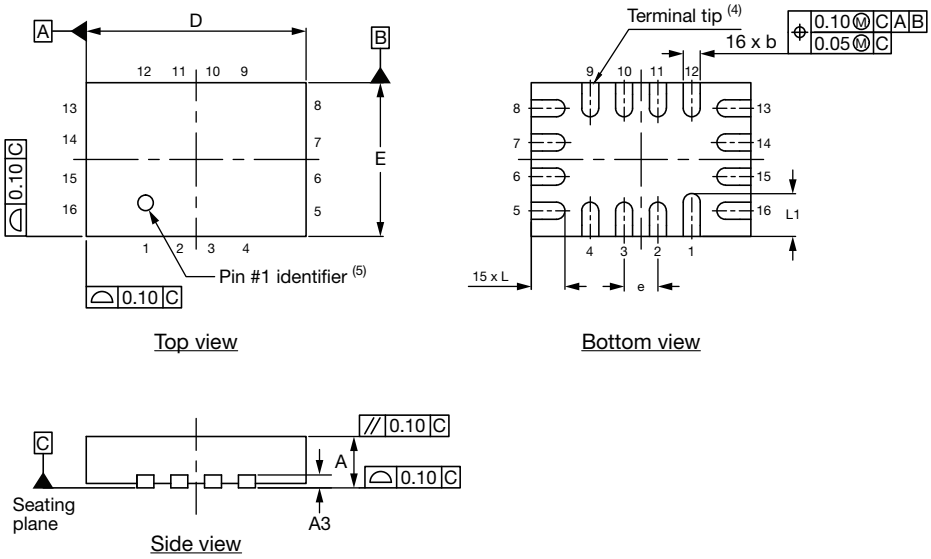


Figure 8. Source, Drain Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?69828.

Thin miniQFN16 Case Outline



DIMENSIONS	MILLIMETERS (1)			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.50	0.55	0.60	0.020	0.022	0.024
A1	0	-	0.05	0	-	0.002
A3	0.15 ref.			0.006 ref.		
b	0.15	0.20	0.25	0.006	0.008	0.010
D	2.50	2.60	2.70	0.098	0.102	0.106
e	0.40 BSC			0.016 BSC		
E	1.70	1.80	1.90	0.067	0.071	0.075
L	0.35	0.40	0.45	0.014	0.016	0.018
L1	0.45	0.50	0.55	0.018	0.020	0.022
N (3)	16			16		
Nd (3)	4			4		
Ne (3)	4			4		

Notes

(1) Use millimeters as the primary measurement.

(2) Dimensioning and tolerances conform to ASME Y14.5M. - 1994.

(3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.

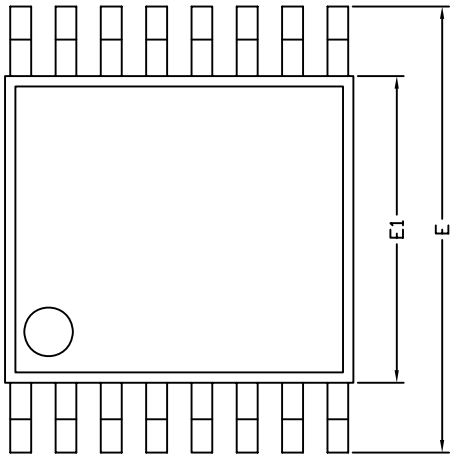
(4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.

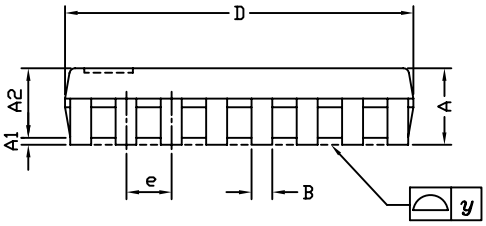
(5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.

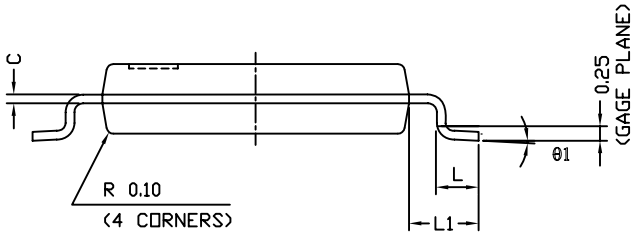
(6) Package warpage max. 0.05 mm.

ECN: T16-0226-Rev. B, 09-May-16
DWG: 6023

TSSOP: 16-LEAD

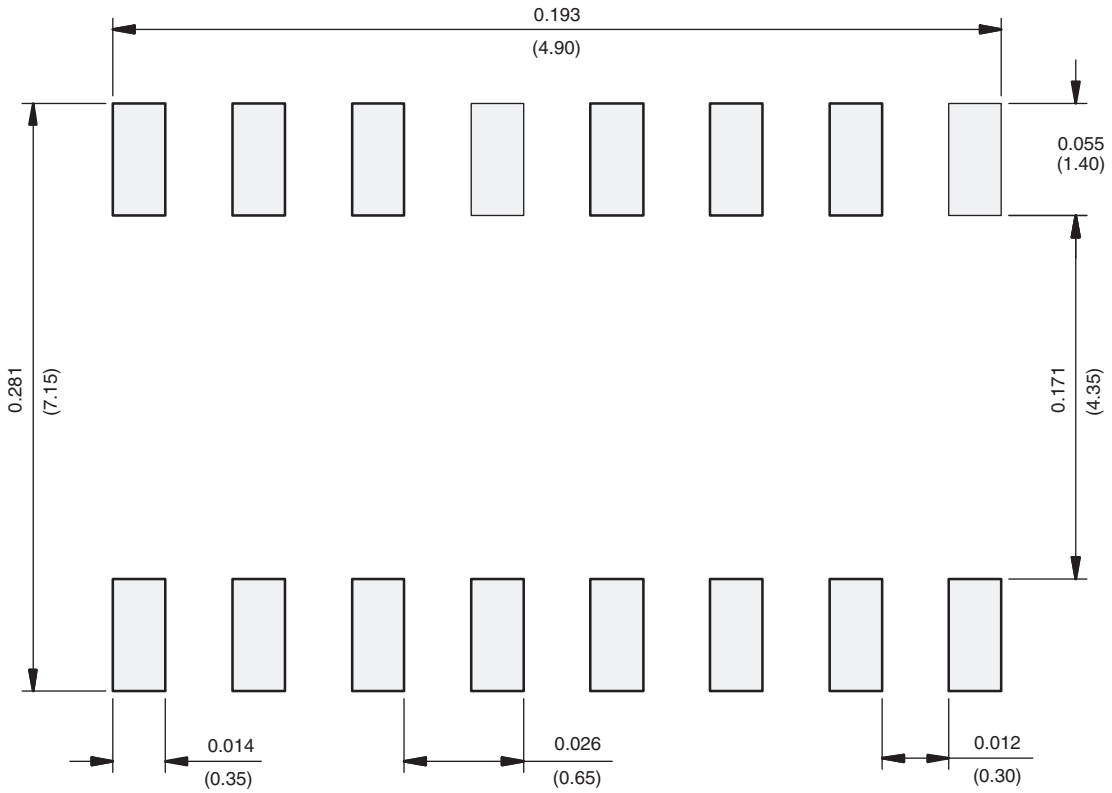






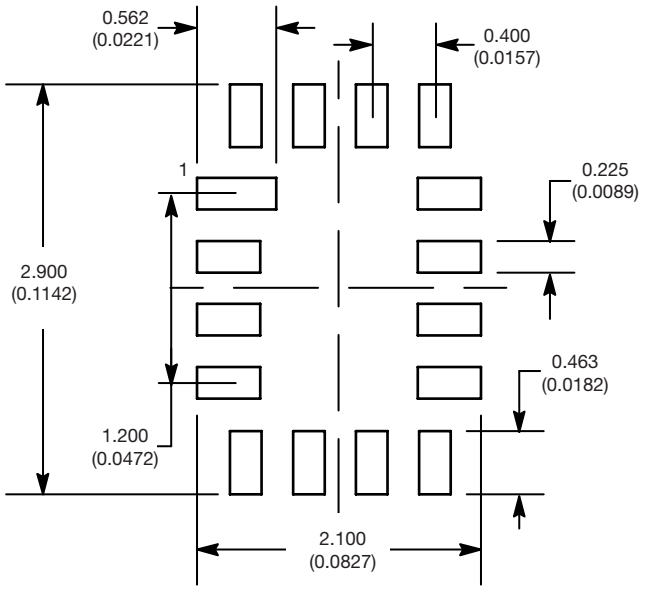
Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06 DWG: 5624			

RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR MINI QFN 16L



Mounting Footprint
Dimensions in mm (inch)

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay’s knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer’s responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer’s technical experts. Product specifications do not expand or otherwise modify Vishay’s terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.